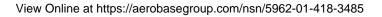
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Memory Microcircuit - Page 1 of 1





Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Terminal Surface Treatment:

Solder

Product Name:

Programmed prom

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

35.00 nanoseconds access

Memory Device Type:

Rom

Terminal Type And Quantity:

32 leadless

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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